



MGBR10L40C

DIODE

DUAL MOS GATED BARRIER RECTIFIER

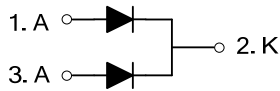
DESCRIPTION

The UTC **MGBR10L40C** is a dual mos gated barrier rectifiers, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed, etc.

FEATURES

- * Low forward voltage drop
- * High switching speed

SYMBOL



ORDERING INFORMATION

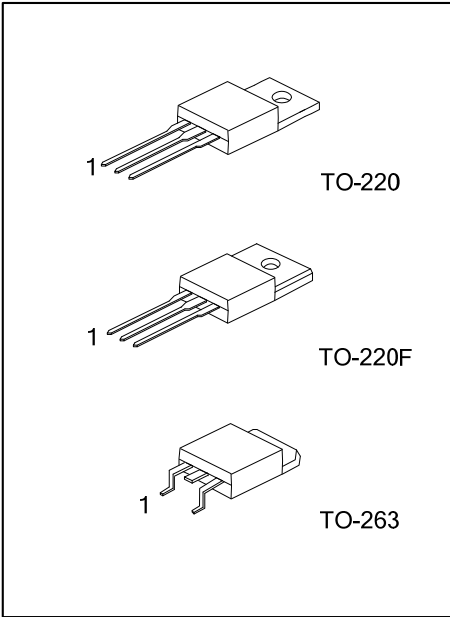
Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
MGBR10L40CL-TA3-T	MGBR10L40CG-TA3-T	TO-220	A	K	A	Tube
MGBR10L40CL-TF3-T	MGBR10L40CG-TF3-T	TO-220F	A	K	A	Tube
MGBR10L40CL-TQ2-T	MGBR10L40CG-TQ2-T	TO-263	A	K	A	Tube
MGBR10L40CL-TQ2-R	MGBR10L40CG-TQ2-R	TO-263	A	K	A	Tape Reel

Note: Pin Assignment: A: Anode K: Cathode

<p>MGBR10L40CL-TA3-T</p>	<p>(1) T: Tube, R: Tape Reel (2) TA3: TO-220, TF3: TO-220F, TQ2: TO-263 (3) L: Lead Free, G: Halogen Free and Lead Free</p>
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MARKING

TO-220 / TO-220F	TO-263



■ ABSOLUTE MAXIMUM RATINGS (PER LEG) ($T_A=25^\circ\text{C}$ unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER		SYMBOL	RATINGS	UNIT
DC Blocking Voltage		V_{RM}	40	V
Working Peak Reverse Voltage		V_{RWM}	40	V
Peak Repetitive Reverse Voltage		V_{RRM}	40	V
Average Rectified Forward Current (Rated VR-20KHz Square Wave) – 50% duty cycle	Per Leg	I_o	5	A
	Total		10	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load		I_{FSM}	120	A
Peak Repetitive Reverse Surge Current (2 μ S-1kHz)		I_{RRM}	2	A
Operating Junction Temperature		T_J	-65 ~ +150	$^\circ\text{C}$
Storage Temperature		T_{STG}	-65 ~ +150	$^\circ\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.
Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

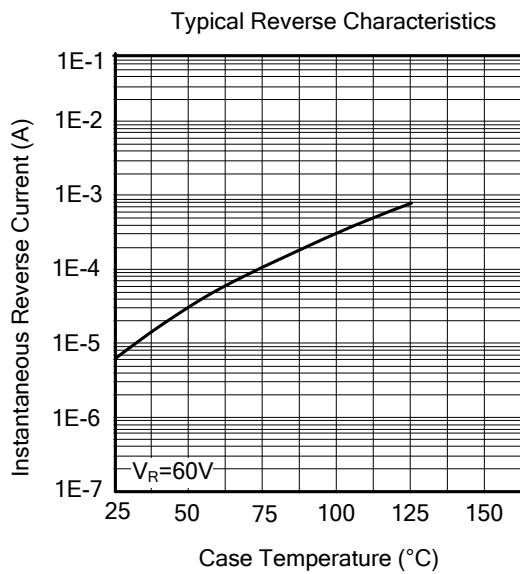
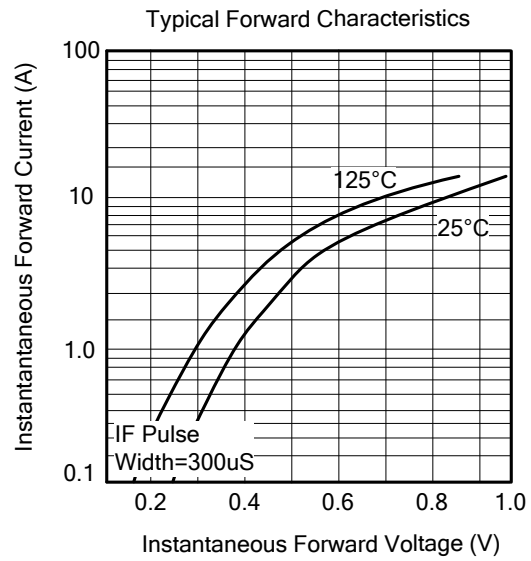
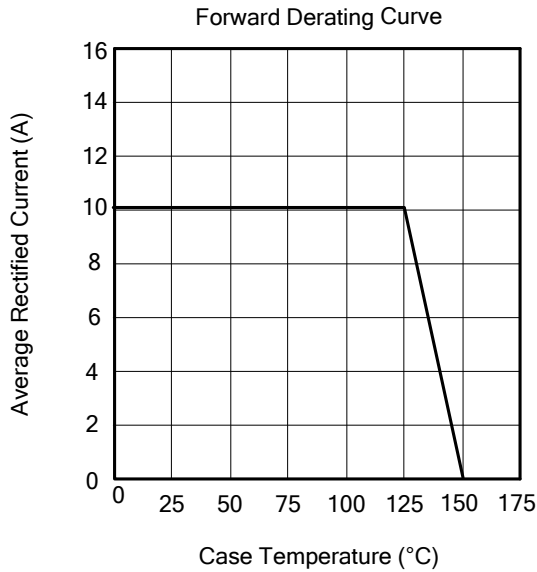
PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient		θ_{JA}	62.5	$^\circ\text{C/W}$
Junction to Case	TO-220/TO-263	θ_{JC}	2	$^\circ\text{C/W}$
	TO-220F		4	

■ ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$, unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	$I_R=0.50\text{mA}$	40			V
Forward Voltage Drop	V_{FM}	$I_F=5\text{A}, T_J=25^\circ\text{C}$			0.55	V
		$I_F=5\text{A}, T_J=125^\circ\text{C}$			0.52	V
Leakage Current (Note 1)	I_{RM}	$V_R=40\text{V}, T_J=25^\circ\text{C}$			500	μA
		$V_R=40\text{V}, T_J=125^\circ\text{C}$			50	mA

Notes: 1. Short duration pulse test used to minimize self-heating effect.
2. Thermal resistance junction to case mounted on heatsink.

■ TYPICAL CHARACTERISTICS



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